



# N-Channel Reduced Q<sub>g</sub>, Fast Switching MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
30	0.008 at V <sub>GS</sub> = 10 V	18		
	0.011 at V <sub>GS</sub> = 4.5 V	15		

# **FEATURES**

Halogen-free According to IEC 61249-2-21 Available

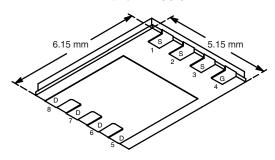


- PWM Optimized for High Efficiency
- New Low Thermal Resistance
- PowerPAK® Package with Low 1.07 mm Profile
- 100 % R<sub>g</sub> Tested





#### PowerPAK SO-8



**Bottom View** 

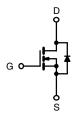
Ordering Information: Si7860DP-T1

Si7860DP-T1-E3 (Lead (Pb)-free)

Si7860DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

#### **APPLICATIONS**

- **Buck Converter** 
  - High Side or Low Side
- Synchronous Rectifier
  - Secondary Rectifier



N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		$V_{DS}$	30		V
Gate-Source Voltage		$V_{GS}$	± 20		V
Continuous Drain Current /T = 150 °C\8	T <sub>A</sub> = 25 °C	I <sub>D</sub>	18	11	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		15	8	
Pulsed Drain Current		I <sub>DM</sub>	± 50		Α
Continuous Source Current (Diode Continuous) <sup>a</sup>		I <sub>S</sub>	4.1	1.5	
Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	30		
Single Pulse Avalanche Energy	L = 0.1 IIII	E <sub>AS</sub>	45		mJ
Manianum Danian Dissinational	T <sub>A</sub> = 25 °C	Ph	5	1.8	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		3.2	1.1	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		
Soldering Recommendations (Peak Temperature) <sup>b,c</sup>				260	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manifestore Investigate Ambient (MOCFFT)	t ≤ 10 s	- R <sub>thJA</sub>	20	25	°C/W	
Maximum Junction-to-Ambient (MOSFET) <sup>a</sup>	Steady State		56	70		
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	1.8	2.3		

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.
- \* Pb containing terminations are not RoHS compliant, exemptions may apply.

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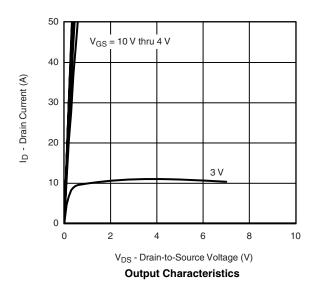
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		3.0	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			1		
		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 70 °C			5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
Drain-Source On-State Resistance <sup>a</sup>	<b>D</b>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 18 A	0.0066		0.008	0	
	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 15 \text{ A}$		0.0090	0.011	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 18 A		60		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 3 A, V <sub>GS</sub> = 0 V		0.70	1.1	V	
Dynamic <sup>b</sup>	<u> </u>						
Total Gate Charge	Qg			13	18		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 18 \text{ A}$		5		nC	
Gate-Drain Charge	$Q_{gd}$			4.0		İ	
Gate Resistance	$R_g$		0.5	1.7	3.2	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			18	27		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 15 $\Omega$		12	18		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ 1 A, $V_{GEN}$ = 10 V, $R_g$ = 6 $\Omega$		46	70	ns	
Fall Time	t <sub>f</sub>			19	30		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 3 A, dI/dt = 100 A/μs		40	70		

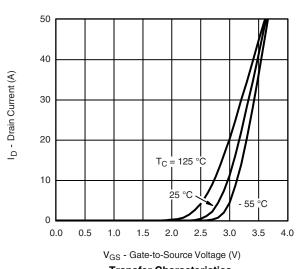
#### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



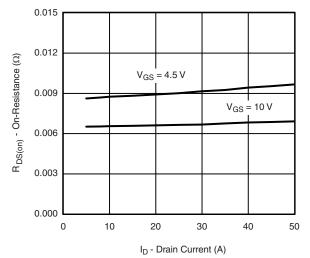




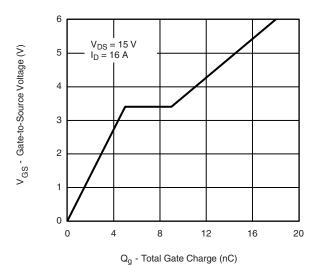




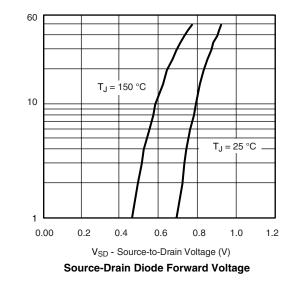
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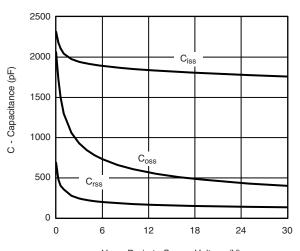


#### On-Resistance vs. Drain Current

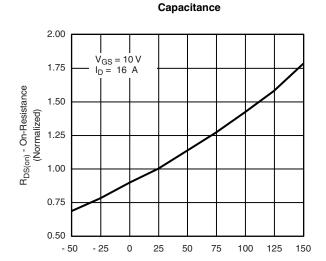


Gate Charge



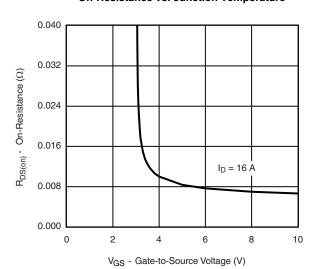


 $V_{\mbox{\footnotesize DS}}$  - Drain-to-Source Voltage (V)



T<sub>J</sub> - Junction Temperature (°C)

On-Resistance vs. Junction Temperature



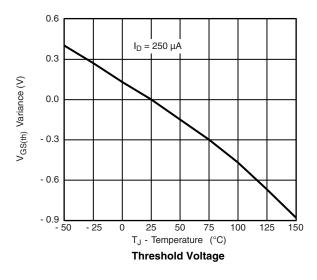
On-Resistance vs. Gate-to-Source Voltage

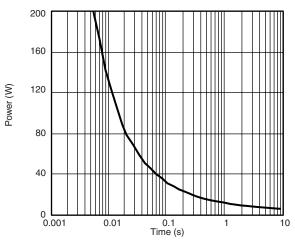
Is - Source Current (A)

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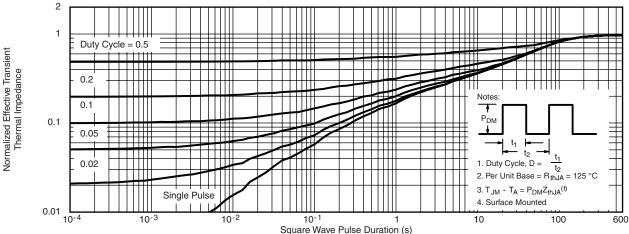
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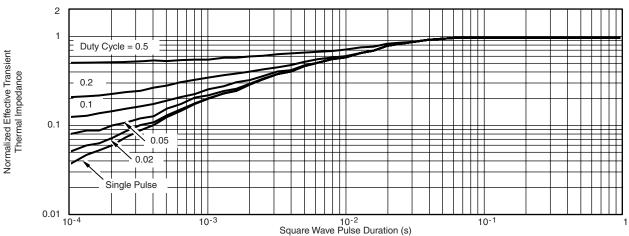




Single Pulse Power, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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